

# PRODUCT RELIABILITY REPORT FOR

**DS7505**, Rev A1

# **Maxim Integrated Products**

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## Prepared by:

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#### Conclusion:

The following qualification successfully meets the quality and reliability standards required of all Maxim products:

In addition, Maxim's continuous reliability monitor program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards. The current status of the reliability monitor program can be viewed at http://www.maxim-ic.com/TechSupport /dsreliability.html.

#### **Device Description:**

A description of this device can be found in the product data sheet. You can find the product data sheet at http://dbserv.maxim-ic.com/l\_datasheet3.cfm.

### **Reliability Derating:**

The Arrhenius model will be used to determine the acceleration factor for failure mechanisms that are temperature accelerated.

```
AfT = \exp((Ea/k)^*(1/Tu - 1/Ts)) = tu/ts
```

AfT = Acceleration factor due to Temperature

tu = Time at use temperature (e.g. 55°C)

ts = Time at stress temperature (e.g. 125°C)

k = Boltzmann's Constant (8.617 x 10-5 eV/°K)

Tu = Temperature at Use (°K)

Ts = Temperature at Stress (°K)

Ea = Activation Energy (e.g. 0.7 ev)

The activation energy of the failure mechanism is derived from either internal studies or industry accepted standards, or activation energy of 0.7ev will be used whenever actual failure mechanisms or their activation energies are unknown. All deratings will be done from the stress ambient temperature to the use ambient temperature.

An exponential model will be used to determine the acceleration factor for failure mechanisms, which are voltage accelerated.

```
AfV = exp(B*(Vs - Vu))
```

AfV = Acceleration factor due to Voltage

Vs = Stress Voltage (e.g. 7.0 volts)

Vu = Maximum Operating Voltage (e.g. 5.5 volts)

B = Constant related to failure mechanism type (e.g. 1.0, 2.4, 2.7, etc.)

The Constant, B, related to the failure mechanism is derived from either internal studies or industry accepted standards, or a B of 1.0 will be used whenever actual failure mechanisms or their B are unknown. All deratings will be done from the stress voltage to the maximum operating voltage. Failure rate data from the operating life test is reported using a Chi-Squared statistical model at the 60% or 90% confidence level (Cf).

The failure rate, Fr, is related to the acceleration during life test by:

```
Fr = X/(ts * AfV * AfT * N * 2)
```

X = Chi-Sq statistical upper limit

N = Life test sample size

Failure Rates are reported in FITs (Failures in Time) or MTTF (Mean Time To Failure). The FIT rate is related to MTTF by:

MTTF = 1/Fr

NOTE: MTTF is frequently used interchangeably with MTBF.

The calculated failure rate for this device/process is:

FAILURE RATE: MTTF (YRS): 30408 FITS: 3.8

DEVICE HOURS: 258784 FAILS: 0

Only data from Operating Life or similar stresses are used for this calculation.

The parameters used to calculate this failure rate are as follows:

Cf: 60% Ea: 0.7 B: 0 Tu: 25 °C Vu: 3.7 Volts

The reliability data follows. At the start of this data is the device information. The next section is the detailed reliability data for each stress. The reliability data section includes the latest data available and may contain some generic data. "\*" after DATE CODE denotes specific product data and SEQ No. to identify specific line items in the report for comments when required.

#### **Device Information:**

Process: E35WN-

3P3M,DPE2,NTC,DSD,PDESD,PDRES,Cap,ENPN,DPT,HTO,SgHalo

Passivation: TEOS Ox-Nit 2-Mask Laser/Pass for E35WM; Full BEOL at

SA; PT only in Dallas

Die Size: 61 x 68 Number of Transistors: 13147

Interconnect: Aluminum / 0.5% Copper

Gate Oxide Thickness: 120 Å

DATA RETENTION						
DESCRIPTION	DATE CODE/SEQ	CONDITION	READI	POINT QTY	/ FAILS	FA#
STORAGE LIFE	0730	150C	1000	HRS 77	0	
			T	otal:	0	

					Total:		0	
ELECTRICAL CHA	RACTER	IZATION						
DESCRIPTION	DATE (	ODE/SEQ	CONDITION	REA	ADPOINT	QTY	FAILS	FA#
ESD SENSITIVITY	0746	* 1	EOS/ESD S5.1 HBM 500 VOLTS	1	PUL'S	3	0	
ESD SENSITIVITY	0746	* 2	EOS/ESD S5.1 HBM 1000 VOLTS	1	PUL'S	3	0	
ESD SENSITIVITY	0746	* 3	EOS/ESD S5.1 HBM 2000 VOLTS	1	PUL'S	3	0	
ESD SENSITIVITY	0746	* 4	EOS/ESD S5.1 HBM 3000 VOLTS	1	PUL'S	3	0	
ESD SENSITIVITY	0746	* 5	EOS/ESD S5.1 HBM 4000 VOLTS	1	PUL'S	3	0	
ESD SENSITIVITY	0746	* 6	EOS/ESD S5.1 HBM 8000 VOLTS	1	PUL'S	3	3	No FA
LATCH-UP	0746	* 7	JESD78, I-TEST 125C			6	0	
LATCH-UP	0746	* 8	JESD78, V-SUPPLY TEST 125C			6	0	
					Total:		3	

OPERATING LIFE									
DESCRIPTION	DATE CODE/S	SEQ CONDITION	N		READ	POINT	QTY	FAILS	FA#
HIGH TEMP OP LIFE	0705	125C, 3.6 V	OLTS		1000	HRS	77	0	
HIGH TEMP OP LIFE	0711	125C, 5.5 V	OLTS		1000	HRS	45	0	
HIGH TEMP OP LIFE	0713	125C, 5.5 V	OLTS		1000	HRS	77	0	
HIGH TEMP OP LIFE	0730	125C, 5.5V	(PSA) & 3.0V (F	SB)	1000	HRS	45	0	
HIGH TEMP OP LIFE	0746 * 1	125C, 3.7 V	OLTS		192	HRS	77	0	
-					•	Total:		0	
W/E ENDURANCE	AND DATA RE	ET'N							
DESCRIPTION	DATE CODE/S	SEQ CONDITION	N		READ	POINT	QTY	FAILS	FA#
WRITE CYCLE STRESS (KCYS)	0705	25 C, 3.6 V	OLTS		200	KCYS	77	0	
STORAGE LIFE	0705	150C			1000	HRS	77	0	
WRITE CYCLE STRESS (KCYS)	0711	85 C, 5.25 \	VOLTS		30	KCYS	77	0	
STORAGE LIFE	0711	150C			500	HRS	77	0	
WRITE CYCLE	0711	85 C, 5.5 V	OLTS		50	KCYS	77	0	
STRESS (KCYS) STORAGE LIFE	0711	150C			1000	HRS	77	0	
WRITE CYCLE	0713	70 C, 5.5 V	OLTS		30	KCYS	77	0	
STRESS (KCYS) STORAGE LIFE	0713	150C			1000	HRS	77	0	
WRITE CYCLE	0723	85 C, 5.25 \	VOLTS		30	KCYS	77	0	
STRESS (KCYS) STORAGE LIFE	0723	150C			500	HRS	77	0	
WRITE CYCLE	0723	85 C, 5.25 \	VOLTS		30	KCYS	77	0	
STRESS (KCYS) STORAGE LIFE	0723	150C			500	HRS	77	0	
WRITE CYCLE	0746 * 3	25 C, 3.7 V	OLTS		80	KCYS	77	0	
STRESS (KCYS) STORAGE LIFE	0746 * 3	150C			96	HRS	77	0	
WRITE CYCLE	0746 * 1	85 C, 3.7 V	OLTS		20	KCYS	77	0	
STRESS (KCYS) STORAGE LIFE	0746 * 1	150C			144	HRS	77	0	
						Total:		0	
FAILURE RATE:	MT	TF (YRS):	30408	FITS:		3.8			
	DEVICE H		258784	FAILS:		0			